



18 GHz SMA N/O S.P.10T. SWITCH

OPTIONS : INDICATOR / TTL DRIVE / SUPP.DIODES

R F CHARACTERISTICS

NUMBER OF WAYS : 10
 FREQUENCY RANGE : 0 - 18 GHz
 IMPEDANCE : 50 Ohms

FREQUENCY (GHz)	0 - 3	3 - 8	8 -12.4	12.4-15.5	15.5- 18
V.S.W.R <=	1.20	1.30	1.40	1.50	1.70
INSERT. LOSS <=	0.20 dB	0.30 dB	0.40 dB	0.50 dB	0.70 dB
ISOLATION >=	80 dB	70 dB	60 dB	60 dB	55 dB
AVER. POWER (*)	240 W	150 W	120 W	110 W	100 W

ELECTRICAL CHARACTERISTICS

ACTUATOR : NORMALLY OPEN
 NOMINAL CURRENT AT 25° C (+10%) : 250 mA
 ACTUATOR VOLTAGE (Vcc) : 12V (10.2 to 13V) / NEGATIVE COMMON
 TERMINALS : solder pins (250 deg.C max./30 sec.)
 INDICATOR RATING : 1 W / 30 V / 100 mA
 TTL INPUTS (E) - High level : 2.2 to 5.5V / 800µA at 5V
 - Low level : 0 to 0.8V / 20µA at 0.8V

MECHANICAL CHARACTERISTICS

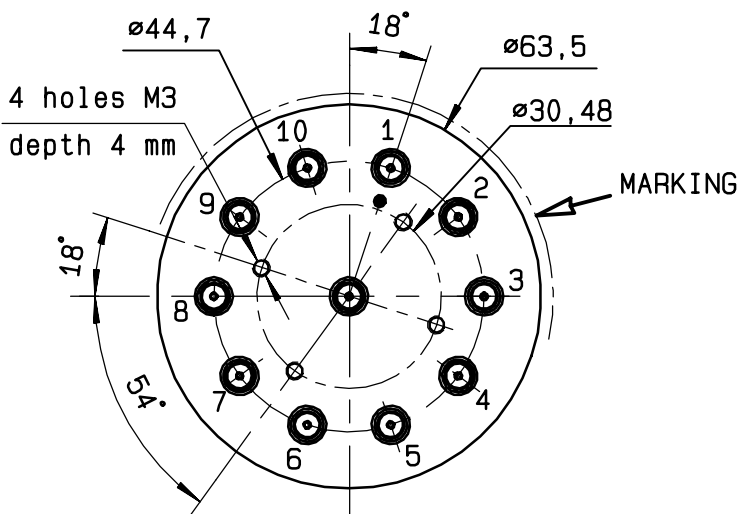
CONNECTORS : SMA female per MIL-C 39012
 LIFE : 2.000.000 cycles per position
 SWITCHING TIME (nominal voltage;25° C) : < 15 ms
 CONSTRUCTION : splashproof
 WEIGHT : < 360 g

ENVIRONMENTAL CHARACTERISTICS

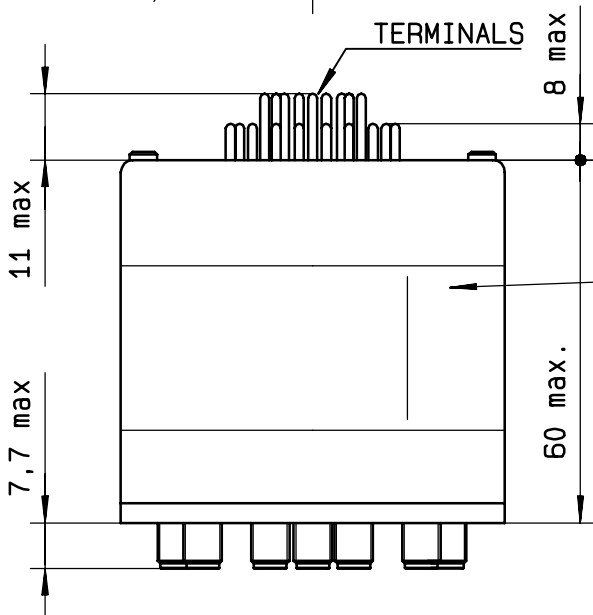
OPERATING TEMPERATURE RANGE (°C) : -40 , +85
 STORAGE TEMPERATURE RANGE (°C) : -55 , +85

(* : average power at 25° C per RF path)

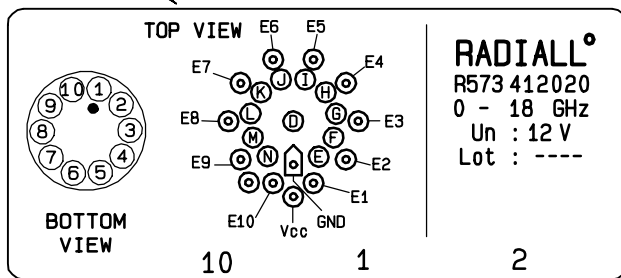
This information is given as an indication. In the continual goal to improve our products, we reserve the right to make any modifications judged necessary



TTL input	RF continuity	Ind.
E1 = 1	IN ↔ 1	D.E
E2 = 1	IN ↔ 2	D.F
E3 = 1	IN ↔ 3	D.G
E4 = 1	IN ↔ 4	D.H
E5 = 1	IN ↔ 5	D.I
E6 = 1	IN ↔ 6	D.J
E7 = 1	IN ↔ 7	D.K
E8 = 1	IN ↔ 8	D.L
E9 = 1	IN ↔ 9	D.M
E10 = 1	IN ↔ 10	D.N

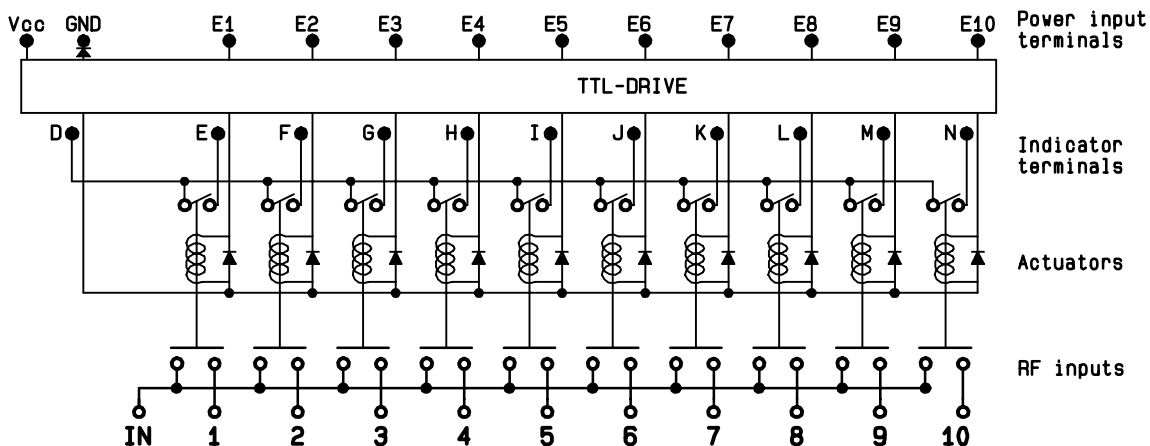


MARKING TOP VIEW (TERMINALS)



RADIALL^o
R573 412020
0 - 18 GHz
Un : 12 V
Lot : ----

SCHEMATIC DIAGRAM



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